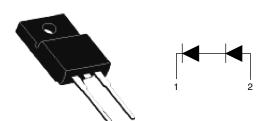


Vishay High Power Products

Hyperfast Rectifier, 15 A FRED PtTM



2L TO-220 FULL-PAK

PRODUCT SUMMARY				
t _{rr}	20 ns			
I _{F(AV)}	15 A			
V _R	600 V			

FEATURES

- Hyperfast recovery time
- · Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- Designed and qualified for industrial level

DESCRIPTION

loading factor.

15S2TH06FP 600 V series are the state of the art tandem hyperfast recovery rectifiers: excellent switching performance and extremely low forward voltage drop trade off is overcome, boosting overall application performance. Specially designed for CCM PFC application, these devices show incomparable performance in every current intensive

hard switching application.

Optimized reverse recovery stored charge enables downsizing of boosting switch and cooling system, increased operating frequency make possible use of smaller reactive elements. Cost effective PFC application is then possible with high efficiency over wide input voltage range and

Plastic insulated package features easy mounting together with not insulated parts.

ABSOLUTE MAXIMUM RATINGS FOR BOTH DIODES					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Repetitive peak reverse voltage	V_{RRM}		600	V	
DC forward current	I _F	T _C = 73 °C	15	٨	
Non-repetitive peak surge current	I _{FSM}	T _C = 25 °C	115	Α	
Operating junction and storage temperatures	T _J , T _{Stg}		- 55 to 175	°C	

ELECTRICAL SPECIFICATIONS FOR BOTH DIODES (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	$I_R = 100 \mu A$	600	-	-	
Forward voltage V _F	I _F = 15 A	-	2.2	2.4	V	
	V_{F}	I _F = 15 A, T _J = 125 °C	-	1.9	2.1	
	I _F = 15 A, T _J = 150 °C	-	1.8	2		
		$V_R = V_R$ rated	-	< 1	10	
Reverse leakage current	I _R	$T_J = 125 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	10	100	μΑ
		$T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	40	200	
Junction capacitance	C _T	V _R = 600 V		17	-	pF

Document Number: 94555 Revision: 07-Apr-08

New Product

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DYNAMIC RECOVERY CHARACTERISTICS FOR BOTH DIODES (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t _{rr}	$I_F = 1.0 \text{ A}, dI_F/dt = -50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	-	28	
Reverse recovery time		T _J = 25 °C	I _F = 15 A dI _F /dt = - 200 A/μs - V _R = 390 V	-	20	-	ns
		T _J = 125 °C		-	45	-	
Peak recovery current I _{RRM}	I _{RRM}	T _J = 25 °C		-	2.6	-	А
		T _J = 125 °C		-	5.6	6.5	_ A
Reverse recovery charge Q _{ri}	Q _{rr}	T _J = 25 °C		=	28	=	nC
		T _J = 125 °C		-	140	-	I IIC

THERMAL - MECHANICAL SPECIFICATIONS FOR BOTH DIODES						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55	-	175	°C
Thermal resistance, junction to case	R _{thJC}		-	-	3.9	°C/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	- *C/VV
Weight			-	2.0	-	g
Weight		-	0.07	-	OZ.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style 2L TO-220 FULL-PAK	15S2TH06FP			

Document Number: 94555 Revision: 07-Apr-08



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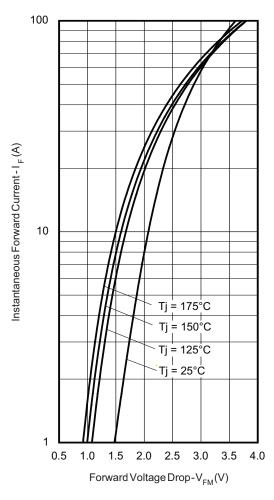


Fig. 1 - Maximum Forward Voltage Drop Characteristics

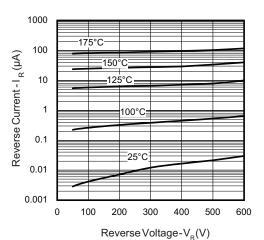


Fig. 2 - Typical Values of Reverse Current vs.
Reverse Voltage

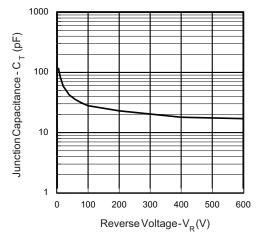


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

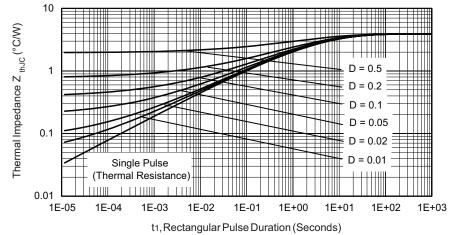


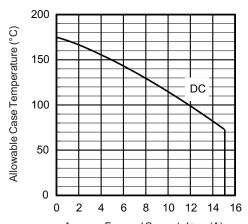
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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 $\label{eq:continuity} \mbox{Average Forward Current-} \mbox{IF}_{(AV)}(A) \\ \mbox{Fig. 5 - Maximum Allowable Case Temperature vs.} \\ \mbox{Average Forward Current}$

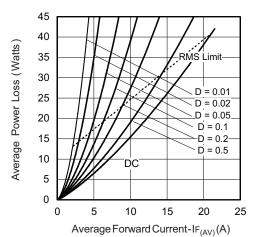


Fig. 6 - Forward Power Loss Characteristics

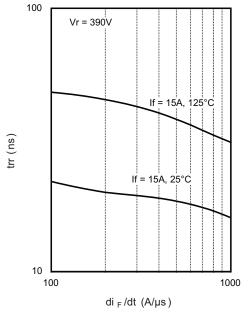


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

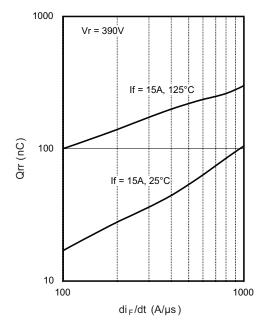


Fig. 8 - Typical Stored Charge vs. dI_F/dt

LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95263				
Part marking information	http://www.vishay.com/doc?95265			



Vishay

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Revision: 18-Jul-08

Document Number: 91000 www.vishay.com